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Chapter 2

Characterization of the Electronic Structure of Spinel Superconductor LiTi$_2$O$_4$ using Synchrotron X-ray Spectroscopy

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1. Introduction

Numerous studies on high-transition temperature ($T_c$) superconductivity were motivated primarily by the intention to explore the nature of cuprates. Experimental results, particularly those based on hard X-ray absorption spectra, show that Cu ions reveal a mixed valence and are accountable for high-$T_c$ superconductivity. Recently discovered iron-based superconductors with perovskite blocking layers [i.e., LnFeAsO (Ln = lanthanide), BaFe$_2$As$_2$, KFeAs, FeSe, and FeAs] have received considerable attention similar to cuprate superconductivity, which was first explored in the 1980s. New superconducting compounds and non-cuprate superconductors with magnetic elements, particularly 3$d$ transition metals, have been widely analyzed by various scholars. Spinel LiTi$_2$O$_4$ (LTO) is a titanium (Ti)-based superconductor that is considered an exotic BCS $s$-wave superconductor with a $T_c$ of ~12 K [21]. This superconductor is regarded as such because it can be described using electron–phonon interaction within the framework of the BCS model [43]. Of the more than 200 typical compounds with an AB$_2$O$_4$ normal spinel structure, in which low-valent-state cation “A” occupies the tetrahedral (8a, $T_d$) interstitial sites and high-valent-state cation “B” occupies the octahedral (16d, $O_h$) sites, only a few exhibit superconductivity, including CuV$_2$S$_4$ ($T_c = 4.5$ K), CuRh$_2$S$_4$ ($T_c = 4.8$ K), and CuRhSe$_4$ ($T_c = 3.5$ K). LTO is the only known spinel oxide superconductor, and it has the highest $T_c$ among superconductors with a spinel structure. The 3$d$ transition metals occupying the $O_h$ sites in spinel oxides may generally exhibit antiferromagnetism, ferromagnetism, and charge/orbital ordering. The nature of magnetic and electronic properties depends on the average valence of the cations. The closely related case of LiV$_2$O$_4$ (LVO), which is an isostructural compound, exhibits distinct physical properties. LVO is the closest neighbor to LTO, and it contains a mixed-valence system with an equal ratio of V$^{3+}$ ($S = 1$) and V$^{4+}$ ($S = \frac{1}{2}$). LVO exhibits
strong electronic correlation, resulting in a greatly enhanced effective mass. The resistivity of this compound displays a metallic character. Although LVO is not a superconductor, it exhibits a heavy fermionic behavior typically observed in a Ce-based (4f electron) system [2, 22].

Similar to cuprates [6, 33] and pnictides [9, 24], Ti-based superconductors (titanate) present the possibility of a mixed-valence state (with electronic configuration of $3d^{0.5}$, equal ratio of Ti$^{3+}$ of spin $S = 1/2$ and Ti$^{4+}$ with $S = 0$) in the ground state. Given that magnetic impurities can suppress the superconductivity of various materials, an investigation into whether the dilute doping of magnetic ions in LTO results in the complete suppression of superconductivity must be conducted. Such an undertaking may provide valuable insights into the mechanism of superconductivity. A previous research observed a rapidly suppressed superconducting $T_c$ in magnetically doped system LiTi$_{1-x}$M$_x$O$_4$ (M = Cr and V) [19]. Among the explored dopants, vanadium (V) was determined to be more effective in decreasing $T_c$ even at small proportions, and it was also observed in other 3d transition metals (e.g., Cr, Mn, Fe, etc.). The results of the study not only signified the magnetic influences and other mechanisms for $T_c$ suppression, but also the charge density wave and structural distortion. For V-doped LTO, the $T_c$ of LTO decreases with V at 2% proportion from ~13 K to ~5 K [18, 19, 24, 49]. These superconducting activities in such a series may unravel the mechanism of superconductivity. Material study on the atomic/electronic structure has essentially illuminated the understanding of its electron transportation properties. Studies have investigated the electronic structure of LTO [8, 39]. The decrease in superconductivity of V-doped LTO is discussed based on a pair-breaking mechanism [19] and a crystalline distortion from octahedral symmetry [34]. The change of Ti and V valence states is suggested to be thoroughly linked to their chemical and physical properties. Electron–electron interaction cannot be overlooked because magnetic ions occupy the structures [32]. In this event, the mechanism of superconductivity remains unknown.

The atomic and electronic structures of the novel spinel LTO superconductors have been investigated. X-ray spectroscopy, X-ray absorption near-edge structure (XANES) spectroscopy, and resonant inelastic soft X-ray scattering (RIXS) spectroscopy are powerful tools for obtaining information on the local orbital character of a specific element. These approaches are also used to probe occupied or unoccupied electronic states near the Fermi level ($E_F$) and the structural symmetry of mixed-oxide systems. However, these spectroscopic techniques are sensitive to atomic symmetry because edge-sharing charge and charge distribution induce electron–electron and electron-orbital interactions, which may be related to the magnetic nature of the transition metal systems.

XANES spectroscopy is a sensitive tool that can be employed to probe unoccupied electronic states above $E_F$ and to analyze the structural symmetry of mixed-oxide systems [10, 12]. It can provide details on the electronic–orbital interaction from the transition metal 3d-O 2p hybridization states and the symmetry of the atomic structure. Therefore, the Ti L- and K-edges can be used to determine the valence states of Ti ions in LiTi$_{2-x}$V$_x$O$_4$ (LTO). The V ions occupying and doped in the O$_6$ site may distort the crystal structure of LTO because of the bonding of O–Ti–O as well as the unoccupied states in the 3d orbitals [34].

RIXS spectroscopic technique is used to explore the electronic structure of materials and to associate the structure with the XANES spectrum. RIXS is a process that describes the de-
excitation of the final state of X-ray absorption, providing information on ground state via the excited intermediate states. Consequently, by tuning various excitation energies, certain RIXS features can be enhanced, allowing the separation of different electronic configurations in the mixed ground states [11, 30, 42]. The above conditions indicate that RIXS is a complementary tool compared with XANES. Unlike XANES, RIXS can be used to investigate a forbidden electronic transition (e.g., d-d or f-f excitation) because it involves two dipole-allowed transitions, given that its final state has symmetry similar to that of the initial state of the former. The RIXS of TM L-edge can reflect the 3d partial density of states and is regarded as a useful approach for analyzing the electron correlation among strongly correlated materials [31, 36, 45] as well as the charge transfer between TM 3d and O 2p orbitals.

In this research, XANES and RIXS spectra were applied to understand the influence of V doping on the atomic/electronic properties of the LTVO system and to discuss the basis of the quick suppression of superconductivity. The occupied or unoccupied states near \( E_F \) of a solid-state solution may be a useful starting point in obtaining fundamental information on the complicated behavior of materials, including ferrites, high-\( T_c \) superconductors, and strongly correlated and ladder systems. These properties demonstrate that magnetic behavior and atypical physical and chemical characteristics can be synthesized and analyzed. The obtained X-ray spectra reveal that the rapidly suppressed superconductivity is associated with the variation of Ti-O hybridization mainly at \( e_g \) bands rather than with the magnetic nature of the substituted V ion.

2. Experiments

All the LTVO samples were synthesized through conventional two-step solid-state reactions with highly pure oxides of TiO\(_2\) (99%), Li\(_2\)CO\(_3\) (99.99%), and V\(_2\)O\(_3\) (99%) [19]. The samples were dried at 150 °C for at least 2 h. Additional Li\(_2\)CO\(_3\) (5 mol%) was added into the samples to compensate for lithium evaporation at high temperature. These processes were performed in a dynamic vacuum environment. In the first step, a mixture of Li\(_2\)CO\(_3\) and TiO\(_2\) was pulverized and calcined at 750 °C for 8 h in ambient air. The mixture was pulverized and calcined again at 800 °C for 12 h to form the intermediate compound Li\(_2\)Ti\(_2\)O\(_5\). In the second step, the stoichiometric powders of Li\(_2\)Ti\(_2\)O\(_5\), Ti\(_2\)O\(_3\), and V\(_2\)O\(_3\) were mixed and ground and then cold-pressed into pellets. The pellets were wrapped with gold foil and sintered in an alumina crucible at 880 °C for 24 h in a dynamic vacuum environment at less than 10\(^{-5}\) torr. The final products were stored in an Ar-filled glove box or vacuum desiccator to prevent aging. Powder X-ray diffraction (XRD) patterns [19] with X-ray (Cu, \( K_\alpha =1.5418 \) Å) radiation in a diffractometer (Philips PW3040/60) confirmed the phase purity of the product and showed the variation of the lattice parameter as a function of V dopant. Different proportions of the dopant up to 2% were selected to understand the effect of dilute doping. Oxygen stoichiometry was expected to remain constant for all small concentrations given that the preparations were all the same.

XANES spectra were obtained from the National Synchrotron Radiation Research Center (Taiwan) and were operated at 1.5 GeV with a current of 360 mA. The K-edge of Ti and V K-
edge of LTVO were measured with a wiggler beamline BL17C1 equipped with Si (111) crystal monochromators. The absorption spectra were recorded in the fluorescence-yield mode with a Lytle detector [27]. These hard X-ray absorption spectra, which could provide information on the unoccupied states with transition metal $p$ state, were normalized to a unit step height in the absorption coefficient from below to above the edges. The oxide powders, namely, TiO$_2$, VO$_2$, Ti$_2$O$_3$, and V$_2$O$_3$, and standard metal foils were used for energy calibration and for comparing the electronic valence states. The XANES spectra at the Ti L- and O K-edges were determined at beamline BL20A in the total-electron-yield mode using an ultrahigh-vacuum chamber with pressure of $\sim 5 \times 10^{-9}$ torr. All spectra were normalized with the standard procedure.

The experiments for X-ray emission spectroscopy (XES) were conducted at beamline 7.0.1 at the Advanced Light Source, Lawrence Berkeley National Laboratory. The beamline is armed with a spherical grating monochromator and an undulator (period 5 cm in 99 poles) [3]. The RIXS spectra were recorded with a high-resolution grating spectrometer at grazing incidence with a 2D detector [17]. The resolution for Ti L emission spectra was about 0.4 eV. The monochromator resolution was set up similar to that of the emission measurements.

X-ray absorption at the Ti L-edge determined that the electron in the Ti 2$p$ core level was excited to the unoccupied Ti 3$d$ and 4$s$ orbitals. XES recorded the signal from the decay process related to the partial densities of Ti 4$s$ and 3$d$ states. RIXS spectra were acquired by tuning different excitation energies according to the x-ray absorption spectral profile to measure XES. Sample current mode was employed to record XANES with an energy resolution of $\sim 0.15$ eV. Meanwhile, a high-resolution grazing-incidence grating spectrometer with a 2D multi-channel plate detector was used to record XES at a resolution of 0.6 eV [36].

3. Results and discussion

3.1. Structure of LTVO

The crystal structure of cubic spinel LTO, which belongs to the Fd3m space group, is illustrated in Fig. 1(a). The structure demonstrates that the lattice parameter of LTO is 8.404 Å ($a = b = c$) and contains eight AB$_2$O$_4$ units per unit cell. In general, a spinel structure has a total of 56 ions, 32 anions, and 24 cations per unit cell. The Li, Ti, and oxide ions are located at tetrahedral (T$_d$) A-sites, octahedral (O$_h$) B-sites, and 32e sites, respectively. The XRD patterns of LiTi$_{2-x}$V$_x$O$_4$ ($x = 0, 0.05, 0.01, 0.015, \text{ and } 0.02$) are shown in Fig. 2(a). The result of the chemical analysis (determined with ICP-AES) is consistent with the nominal composition [19, 18, 24, 49]. These patterns reflect that the crystal structure is of pure spinel structure without an impure phase. The lattice parameter of LTVO samples displayed in Fig. 2(b) linearly decreases with the increasing concentration of the dopant. Doping V, which has a smaller ionic radius, induces a change in the lattice parameter when in a Ti site. This lattice shrinkage can be attributed to the fact that the ionic radius of V$^{3+}$ (0.64 Å) is smaller than that of Ti$^{3+}$ (0.67 Å) in the O$_h$ site [29]. The rate of shrinkage of the lattice parameter is $\sim 3.6$ Å/at% based on the occupancy of O$_h$ sites. This rate is also related to the bond length between the cations (Ti and V) and oxygen. Electronic...
structure strongly depends on the hybridization states of the transition metal 3d-O 2p orbitals nearby E_F when electronic exchange normally occurs. Thus, the changed electronic structure around the transition metal ions greatly affects the oxidation state and physical properties of the latter. Considering these physical properties in AB_2O_4 with mixed-valence states require wide-ranging knowledge of their electronic structure, particularly the p-d hybridization and spin-orbital symmetry. Several experiments and theories show that AB_2O_4 exhibits strong electron–hole correlations because of the TM ions located in various sites [8, 39].

Figure 1. Crystal structure of LTO [Li (green), Ti (blue), and O (grey)].

3.2. Resistive properties

The transport properties of the samples are specified in Fig. 3(a) with V doping of less than 0.025. The findings indicate that the superconducting T_c is suppressed with an increasing proportion of the dopant. Fig. 3(c) reveals that the resistivity of the samples gradually increases. The un-doped LTO has a superconducting T_c of ~12 K with a transition width (△T_c) of ~0.4 K. Fig. 3(b) indicates that when the Ti ion is replaced with V ions, T_c exhibits an abrupt but linear suppression with respect to the level of doping. Given the magnetic pair-breaking effects [47].
the doped magnetic ions suppress superconductivity. Considerable research has been devoted to exploring cuprate [48]; Tarascon et al., 1987) and pnictide [41] superconducting systems based on resistivity measurements. For the LTO series, the effect of doping with both non-magnetic and magnetic impurities at both Td and Oh sites on (Li1-xAx)(Ti2-yBy)O4 [A = Mg and Mn; B = Al and Cr] compounds has been previously reported [26]. The substitution of non-magnetic ions (e.g., Mg2+ at the Td site and Al3+ at the Oh site) slightly suppresses superconductivity similar to the case when Li+ ions occupy the Td site. However, the effect of superconductivity suppression is greater when the magnetic Mn2+ ions occupy the Td site. The suppression of superconductivity is attributed to pair-breaking when the Cooper pairs are scattered with magnetic impurities. The effect of substituting Ti3+ with Cr3+ at the Oh site is even more significant.

Figure 3. (a) Transport properties of LTO and LTVO samples at low temperature without magnetic field. (b) Chemical composition of V-dependence of superconducting Tc. (c) Resistivity at room temperature.

The resistivity near 300 K increases as x increases [Fig. 3(c)], indicating the extreme sensitivity of the transport properties to the electronic effect of 3d transition metals. The itinerant carrier density can be attributed to the cation (Ti3+) in LTO. Similar to the reports of a previous study on Al-doped LTO [16], the results of the current study clarify the effect of carrier density on superconductivity, such that the resistivity increases with the level of doping in the normal state. Except for the semiconducting behavior at the normal state, a similar Tc has been determined in LiTi1.7Al0.3O4 and LTO samples [19]. This observation implies that Tc is slightly affected by substituting a considerable proportion of the trivalent non-magnetic ions. The ratio Ti3+/Ti4+ in Oh symmetry can then be modulated with impurity doping to vary the superconducting properties of LTO. Electron–electron interaction may be a key factor in causing changes in the transport properties of the samples. By distorting the local symmetry of the spinel structure, V substitution will not only alter the valence of Ti, but the hole/electron effect as well. This phenomenon is discussed in the next section.
3.3. Electronic structure results based on x-ray spectra

With the aim to investigate the effects of V dilute doping on LTO, this research measures XANES and RIXS at Ti L-edges. As shown in the inset in Fig. 4(a), the Ti L-edge XANES spectra exhibit several well-resolved features because of the excitations of a 2p core electron into the Ti 3d empty states, that is, a transition from the ground state with configuration 2p⁶3dₓ²⁻ᵧ² to an excited electronic configuration 2p⁵3dₓ²ᵧ² with numerous multiplet excitations. When the spin-orbital coupling is in the transition metal 2p state, the spectra reveal two prominent features located at the energy ranges of 455 eV to 461 eV and 461.2 eV to 468 eV, corresponding to the absorptions L₃ (2p₃/₂ − 3d) and L₂ (2p₁/₂ − 3d) edge respectively. These prominent features are due to a strong Coulombic interaction between the poorly screened Ti 3d electrons and the Ti 2p core hole [12]. L₂ edge features are normally broadened compared with the L₃ edge because of the lesser lifetime of the 2p₁/₂ core hole (i.e., a radiationless electron transition from energy level 2p₃/₂ to the 2p₁/₂), accompanied by the promotion of a valence electron into the unoccupied states (conduction band). In the Oₓ crystal field, the 3d band splits into t₂g (dₓ²−ᵧ², dₓz, and dᵧz) and e₉ (dₓ²+y² and 3dₓ²−ᵧ²) subbands [Δ = (e₉) − (t₂g) = 10 Dq]. Given the Oₓ crystal-field splitting, the Ti L₂,₃-edge feature possesses t₂g and e₉ bands. The RIXS Ti 3d spectra of LTO and doped LTO (V 2 %) are exhibited with energy-loss scales in Fig. 4(a). Four distinct spectral features are observed in RIXS spectra. These features are as follows: elastic peak at the energy loss at zero, d–d excitations at about 4 eV, a broad-band feature at around 7 eV, and a large energy dispersed-feature above 10 eV. Letters a to k denote the different exciting energies based on the XANES spectra, as displayed in the inset of Fig. 4(a). For example, XES spectrum b is collected by tuning the incident photon energy at 457 eV in XANES. The inelastic scattering features ranging from 5 eV to 10 eV originate from the complicated charge-transfer excitation from O 2p to Ti 3d t₂g and e₉ subbands [1, 31]. The low-energy inelastic scattering features absent in TiO₂ are observed at energy of less than 5 eV [36]. The spectra within this energy range significantly differ from that of TiO₂. The appearance of Ti⁶⁺ implies that an electron occupies the empty 3d t₂g orbitals, thus inducing the energy-loss features. Strong d-electron correlation is revealed because the relative intensities of peaks Aₙ and Bₙ (d–d excitations) are observed to be markedly different at varying excitation energies. An enhanced energy-loss peak is observed at 1 eV in spectrum a, and the intensity of this peak intensively drops when the excitation energy is tuned to a higher energy (peak b in XANES). With the increase of excitation energy at c, another intense peak at energy loss of about 2.9 eV is observed. An excitation energy tuned below the L₃ t₂g peak in the spectrum (letter a) enhances inelastic scattering Aᵣ, which is uncommon. This enhanced inelasticity is not observed at either t₂g (b) or e₉ (d) resonant energy. This phenomenon can be explained by considering the presence of Ti⁶⁺, as revealed by the constant-initial-state absorption spectrum [3]. The spectral shapes in XANES spectra are similar for both LTO and LTVO, wherein spectral differences are slightly small. Given that the spectral change of XANES is small with V doping, the spectral deconvolution and specific electronic state can be measured separately from RIXS [11]. The result at a specific energy (c) in Figs. 4(b) and 4(c) indicates that an enhanced trivalent Ti contribution is observed at a dip quadrivalence within the spectrum (between t₂g and e₉). The Ti⁵⁺ t₂g⁻e₉ resonance energies correspond to the excitation energies 456 and 457.5 eV respectively. [3].
When excitation energy is tuned to the $t_{2g}$ resonance, the low-energy-excited feature $C_4$ at ~1 eV demonstrated in Figs. 4(b) and 4(c) is resonantly enhanced. This feature corresponds to the electron-hole pairs within the $t_{2g}$ band. When the spectrum is acquired with energy at about $e_g$ resonance energy [Fig. 4(c)], the intensity of peak $D_4$ increases. Such an increase can be attributed to the transition between the occupied $t_{2g}$ and the unoccupied $e_g$ states. The presence of this RIXS feature indicates a strong electron–electron association. The $d$-$d$ excitation peak at an energy loss of about 2.9 eV corresponds to the crystal-field splitting (i.e., 10 $D_q$) and refers to the ground state without the core hole. The comparison of the spectra of each set shows that the intensity of the loss feature decreases with the increasing concentration of dopant ($x = 0.02$). Hence, fewer electrons are distributed in the $t_{2g}$ band. In a previous study on TiO$_2$ [31], no obvious feature was exhibited in the region located below the elastic signal (peak). The change in intensity is due to the variation of the incompletely filled $t_{2g}$ band arising from the V doped effect. This result forcefully indicates that the Ti valence is enhanced when V is doped. The active Ti ions in LTO have a formal oxidation state trivalence and quadrivalence, which display nearly 0.5 electrons in the 3$d$ orbital, and possess a lesser electronic density. Doping with V reduces the number of Ti 3$d$ electrons, suggesting an increase in the formal oxidation number of the Ti ion. The Ti ions show a mixed-valence state and contain some $t_{2g}$ electrons in LTO. With no $t_{2g}$ electron, $d$-$d$ excitation is absent because no electron subsists in $t_{2g}$ to be excited to the $t_{2g}/e_g$ unoccupied state. A little variation in valence of Ti is then reflected in the RIXS spectra. The diminution or absence of features in the energy range from 0 eV to 5 eV indicates a decrease in $d$-$d$ transitions. More electrons occupy the $t_{2g}$ orbital when the oxidation number of Ti changes from trivalence to quadrivalence. The probability of exciting the $t_{2g}$ electron into the unoccupied states ($t_{2g}$ or $e_g$) is therefore increased. Only RIXS can observe the $d$-$d$ excitations ($t_{2g}$-$t_{2g}$ and $t_{2g}$-$e_g$) in the spectra. The significance of observing this $d$-$d$ excitation is that the $t_{2g}$ occupation number changes with V doping, whereas the number of $t_{2g}$ electrons decreases with V doping. Therefore, the significant RIXS spectrum can observe this kind of valence change.
Complementary information is also acquired for this research by thoroughly analyzing the XANES Ti L_{3,2}-edge spectra. The spectra of LiTi_{2-x}V_xO_4 (or LTVO) (x = 0 to 0.02) are presented in Fig. 5(a). The white line shapes of the spectra of LTO (undoped) and slight V doping (x = 0.005) in LTO are similar. The A_5 and C_5 features (B_5 and D_5) are previously assigned as the t_{2g} (e_g) states of the 10 Dq crystal-field-split in 3d orbitals. This O_h crystal-field splitting is ~1.8 eV at LTO, but increases from 1.8 eV to 2.0 eV when the V concentration increases from x = 0.005 to x = 0.02. This phenomenon reveals the distortion of O_h symmetry when Ti is replaced with slight V doping. This finding is consistent with the powder XRD results and the theoretical calculations [12, 13, 15]. Moreover, the results specify that B_5 peak broadens with its gradual V doping. As previously reported [12, 13, 15], and according to the Jahn-Teller distortion with ΔE_{J-T} energy splitting in the e_g band, the e_g orbitals point directly toward the Ti 2p orbitals of the octahedrally coordinated O atoms. In general, e_g band is sensitive to the local environment, producing a changed bonding distance and a O–Ti–O angle in the presence of V doping. These e_g-related peaks are also broader than the t_{2g} peak because of the larger hybridization between e_g orbitals and O ligand states, and because of the associated effects of solid-state broadening [12]. The e_g feature appears as a narrow and symmetric profile in LTO, representing symmetric octahedrally coordinated Ti–O bonds. This feature becomes broad and asymmetric upon doping, suggesting a distortion. In particular, distortion may arise from the uneven Ti-O bonds in the O_h symmetry. The e_g peak at the side with greater energy originates from the short Ti-O bonds because of the increase in hybridization (relative to the long Ti-O bonds); hence, the intensity ratio of the high-energy to low-energy e_g peaks is increased with V doping. This result implies that long Ti–O bonds become shorter [17]. An enhancement in the integrated area under A_5 peak implies the increase in unoccupied states of Ti 3d states, thereby indicating that the Ti valence increases with slight V doping. From the Ti–O bond, the electronic configuration of Ti exhibits a combination of 3d^0 (t_{2g}^0e_g^0) and 3d^1 (t_{2g}^1e_g^1) in the ground state. Fig. 5(b) shows
the integrated area of ratio $A_5/B_5$, which clearly increases with V doping. Consequently, the more intense $A_5$ ($t_{2g}$) feature implies a higher oxidation number and exhibits the presence of Ti$^{4+}$ ($3d^0$) [28, 40]. Moreover, the area of the L$_3$-edge that corresponds to ($A_5+B_5$) progressively decreases when V concentration increases [Fig. 5(c)] because V replaces Ti. This trend is in good agreement with the XRD results [18]. A small but actual increase in Ti valence with slight V doping is observed in XANES Ti L$_3$-edge spectra. Such an increase is significantly obvious in the Ti L-RIXS spectra.

The pre-edge features of Ti K-edge XANES spectra are displayed in Fig. 6(a). These spectral features at K-edge are due to the transitions from the Ti 1$s$ core level to the 4$p$-derived final states based on the dipole selection rule. The pre-edge features are a combination of strongly hybridized Ti 4$p$ and 3$d$ and O 2$p$ orbitals. Quadrupole-allowed transitions generally occur at the pre-edge region in the transition metal oxides, which correspond to the contribution from 3$d$ orbitals through 4$p$-3$d$ hybridization [14, 25, 37]. The inset of Fig. 6(a) reveals that a Gaussian function is subtracted from the original Ti K-edge spectrum for a detailed comparison of the pre-edge spectra. Fig. 4(a) shows the Ti K-edge spectra of LTO and LTVO (0.005 to 0.02). As marked by the black arrow in Fig. 6(a), the spectra of LTVO with a small concentration of $x$ from 0.005 to 0.01 are similar to that of LTO with the same photon energy at the main peak $A_6$. The Ti valence performs to maintain +3.5 owing to the smaller concentration of V doping. Nevertheless, the intensity of the pre-peak spectrum increases relative to that of pure LTO as the doping level is increased to $x = 0.015$ and $x = 0.02$. Meanwhile, as directed by the red arrow in Fig. 6(a), chemical shift is also observed as V concentration increases. Fig. 6(b) displays the pre-edge region between 4969 and 4977 eV, as well as the three main features (i.e., $C_6$, $D_6$, and $E_6$) in XANES Ti K-edge spectra of TiO$_2$ (anatase, Ti$^{4+}$) and LTVO ($x = 0$, 0.02) samples. The origin of the splitting of pre-peaks is caused by local excitations (1$s$ to 3$d$ $t_{2g}$ and $e_g$) [5, 14, 38, 46]. Conversely, the greatest contribution to this splitting is suggested to be the corner- and edge-sharing Ti octahedra that yield non-local, intense hybrid excitations. The next-nearest neighbor 3$d$ states ($t_{2g}$ and $e_g$) are related Ti 4$p$ states that absorb atom via the anion O 2$p$ states [7, 23, 44]. The local structure of Ti for LTO and LTVO also possesses O$_h$ symmetry; hence, the pre-peak region ($A_6$ and $B_6$) can be described in terms of a similar scenario [23, 44, 7]. The intensity of these pre-peaks varies with V concentration. In the V-doped LTO, the substitution of V for Ti slightly decreases the lattice parameter [18]. A reduced bond length (Ti–O–Ti) subsequently increases the overlap of the first-nearest-neighbor and the absorbing atom (e.g., Ti 4$p$-Ti 3$d$ orbitals) mediated by O ion. Therefore, these pre-peaks are closely related to the increase in the number of the first-nearest-neighbor unoccupying the Ti 3$d$ states. These intense hybrid peaks intensities increase with the increase of V concentration. The inset of Fig. 6(b) shows that the variation in the area under the pre-peak suggests that the 3$d$ unoccupied states are altered via the interaction of the Ti 4$p$-O 2$p$-Ti 3$d$ states. These results strengthen the conclusion that Ti is in mixed-valence states between LTO and LTVO [14, 24]. The analysis of the spectra of LTO and LTVO ($x = 0.02$) reveals that pre-peaks $A_6$ and $B_6$ are stronger in LTVO than in LTO, attended by a chemical shift of the main peak to higher energy. Therefore, Ti valence is increased when V is doped. The average valence of Ti in the case of doped LTVO ($x = 0.015$ and 0.02) is approximately +3.6, which is obtained with a simple calculation and a fit of the ratio of areas under the spectral lines.
The O K-edge XANES spectra [Fig. 6(c)] provide useful information about the unoccupied density of states in TMO because of the covalent mixing between O and TM ions. The two pre-edge features are at about 530 eV to 536 eV because of the strong hybridizations in Ti 3d–O 2p states, and correspond to the t_{2g} and e_{g} states of Ti 3d orbitals respectively. The intensity of the t_{2g} and e_{g} peaks at the O K-edge changes is similar to an increased peak ratio t_{2g}/e_{g} in Ti L-edge XANES. In sum, the above results specified by the XANES and RIXS spectra strongly confirm that the valence of Ti is increased when the doping level of x increases. Thus, the Ti-O hybridization and electron–electron correlation are modified when a slight doping of V ions completely suppresses the superconductivity of LTO.

Previous studies have indicated that LTO is a spinel superconductor, whereas spinel LVO reveals a heavy fermionic behavior with a Curie-Weiss spin susceptibility and a large electronic specific heat. Conduction arises on a Ti sublattice via the t_{2g} orbitals with a narrow bandwidth (2 eV to 3 eV), displaying possible strong electronic correlations. The origin of the physics and electronic properties of the spinel structure are yet to be resolved. Our current research demonstrates the role of 3d electrons in the properties of LTO and LTVO. The full solid solution of LiTi_{2-\text{x}}V_{\text{x}}O_{4} (0 \leq \text{x} \leq 2) has been investigated [24]. The replacement of V ions for Ti site modifies the bandgap and d electron/hole exchange in Ti energy levels in order to maintain electrical neutrality. Several mechanisms for understanding the quickly suppressed superconductivity with a slight doping of LTVO have been proposed. The slight doping of LTVO may incur two major electronic effects. The first one is a simple pair-breaking effect with electron spin S = 1 on superconductivity [20, 24]. The second one refers to the effect of carrier doping on electron correlation via band filling. The 3d electrons of V are assumed to hybridize the Ti conduction electrons, making them itinerant. A simple magnetic pair-breaking of electron spins induced by additional impurity is commonly assumed to be responsible for suppressing superconductivity based on the localized moments of 3d electrons of V [24]. The localized magnetic moment per V atom is estimated to be 1.7 μB in the V^{4+} state with S = 1/2 [24]. The XANES measurements at V K-edges plotted in Fig. 7 show that V is more likely to be in state 3+ (Bordage et al., 2110), which contains a d^{2} electronic configuration and is supposed to offer a weak magnetic moment probably because of the antiparallel orientation of the electron spins. The decreased V magnetic moment is also obvious in LiZnV_{2}O_{4} [35]. A second possible reason for a weak magnetic moment is the decreased charge carriers at Ti t_{2g} bands. In this case, V electrons are expected to be localized at the Ti conduction electrons. 

The spectra in RIXS reveal a significant variation in the d-d excitation feature, which suggestively decreases when LTO becomes LTVO, even with slight doping of V ions. This situation shows the decreased Ti 3d occupied states with the increase of x concentration. The Ti t_{2g} occupation number is then altered upon V doping. This valence variation is small in XANES Ti K- or L-edges spectra, but weighty in RIXS spectra. The results, particularly the reflection of the decreased intensities of t_{2g}–t_{2g} and t_{2g}–e_{g} transitions from the RIXS spectra,
support the role of these electronic states in rapidly suppressing $T_c$ in slight V doping. Accordingly, the findings of this research support the conclusion that the decreased density of the states of Ti 3$d$ electrons at $E_F$ is responsible for rapidly suppressing superconductivity.

**Figure 6.** (a) XANES Ti K-edge spectra of LTVO ($x = 0$ to 0.2) and Anatase-TiO$_2$ in the pre-edge region. The inset shows that a Gaussian function was subtracted from the original TiO$_2$ spectrum. (b) Detailed comparison of the pre-edge region for LTO and LTVO ($x = 0.02$). (c) XANES O K-edge spectra shown with two main peaks in the pre-edge region corresponding to the hybridization of Ti 3$d$ ($t_{2g}$ and $e_g$)-O 2$p$ states.

**Figure 7.** XANES V K-edge of LTVO ($x = 0.02$) compared with the larger doping of LTVO ($x = 0.05$ and 0.1). No significant variation is observed in the spectra.
4. Conclusion

The results on the effect of V doping on the atomic and electronic structures of LTVO, XAS, and RIXS spectra reveal that the valence of V ions remains constant, but the hybridization of Ti-O considerably varies. In particular, the results show the mixed valency nature of Ti ions and a significant variation in the hybridization of Ti 3d-O 2p states. The sharp decrease in the superconductivity of V-doped samples is ascribed to the electron–orbital interaction arising from the hybridization of TM and O orbitals. Low-energy excitation because of d-d excitation indicates that electron correlation and Ti oxidation number are enhanced, which support the XAS observation. Meanwhile, the observed properties of superconductivity are attributed to an altered density of the states of Ti 3d electrons and Ti-O hybridization. The Ti electronic configuration and lattice distortion induce the rapidly suppressed superconductivity and are attributed to hybridization rather than to the magnetic nature of the substituted ion. This research also demonstrates that RIXS is a powerful tool for investigating the electronic states and electron correlations of Ti compounds, in which the XANES spectral features are subdued.

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